Diode Semiconductor Device - Page 1 of 1



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Meta	d
Over	rall Length:
0.250	0 inches
Term	ninal Length:
0.700	0 inches
Over	rall Diameter:
0.08	5 inches
Mou	nting Method:
Term	ninal
Feat	ures Provided:
Herm	netically sealed case
Sem	iconductor Material:
Silico	n
Volta	age Rating In Volts Per Characteristic:
125.0	0 reverse voltage, peak
Curr	ent Rating Per Characteristic:
2.50	amperes source cutoff current
Maxi	imum Operating Tempurature Per Measurement Point:
175.0	0 degrees celsius ambient air
Term	ninal Type And Quantity:
2 uni	insulated wire lead
Shel	f Life:
N/a	
Unit	Of Measure:
Dem	ilitarization:
No	
Fiig:	
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